1. General description

XC7SH08 is a high-speed Si-gate CMOS device. It provides a 2-input AND function.

2. Features

- Symmetrical output impedance
- High noise immunity
- Low power dissipation
- Balanced propagation delays
- SOT353-1 and SOT753 package options
- ESD protection:
 - HBM JESD22-A114E: exceeds 2000 V
 - MM JESD22-A115-A: exceeds 200 V
 - CDM JESD22-C101C: exceeds 1000 V
- Specified from –40 °C to +125 °C

3. Ordering information

Table 1.Ordering information

| Type number | Package | Package | | | | | | |
|-------------|-------------------|---------|---|----------|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | |
| XC7SH08GW | –40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads; body width 1.25 mm | SOT353-1 | | | | |
| XC7SH08GV | –40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads | SOT753 | | | | |

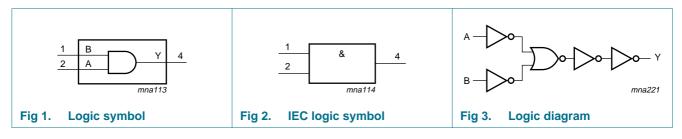
nexperia

4. Marking

| Table 2. Marking codes | |
|--------------------------|------------------------|
| Type number | Marking ^[1] |
| XC7SH08GW | fE |
| XC7SH08GV | f08 |

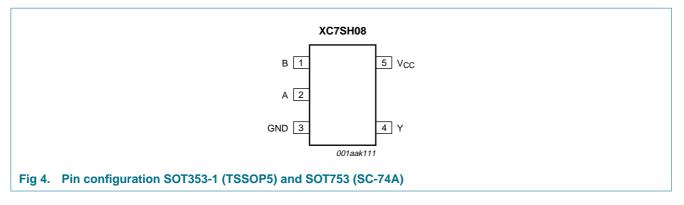
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

| Table 3. | Pin description | |
|-----------------|-----------------|----------------|
| Symbol | Pin | Description |
| В | 1 | data input |
| A | 2 | data input |
| GND | 3 | ground (0 V) |
| Y | 4 | data output |
| V _{CC} | 5 | supply voltage |

7. Functional description

Table 4.Function table

H = *HIGH* voltage level; *L* = *LOW* voltage level

| Inputs | Output | |
|--------|--------|---|
| Α | В | Y |
| L | L | L |
| L | Н | L |
| Н | L | L |
| Н | Н | Н |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|--------------|------|------|
| V _{CC} | supply voltage | | -0.5 | +7.0 | V |
| VI | input voltage | | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | V _I < -0.5 V | -20 | - | mA |
| Ι _{ΟΚ} | output clamping current | V_{O} < -0.5 V or V_{O} > V_{CC} + 0.5 V | <u>[1]</u> _ | ±20 | mA |
| I _O | output current | $-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$ | - | ±25 | mA |
| I _{CC} | supply current | | - | 75 | mA |
| I _{GND} | ground current | | -75 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \ ^{\circ}C$ to +125 $^{\circ}C$ | [2] _ | 250 | mW |
| | | | | | |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For both TSSOP5 and SC-74A packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|-------------------------------------|--|-----|-----|-----------------|------|
| V _{CC} | supply voltage | | 2.0 | 5.0 | 5.5 | V |
| VI | input voltage | | 0 | - | 5.5 | V |
| Vo | output voltage | | 0 | - | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | °C |
| $\Delta t / \Delta V$ | input transition rise and fall rate | V_{CC} = 3.3 V \pm 0.3 V | - | - | 100 | ns/V |
| | | $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$ | - | - | 20 | ns/V |
| | | | | | | |

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | 25 °C | | _40 °C | to +85 °C | −40 °C | to +125 °C | Unit |
|-----------------|--------------------------|---|------|-------|------|--------|-----------|---------------|------------|------|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| VIH | HIGH-level | $V_{CC} = 2.0 V$ | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
| | input voltage | V _{CC} = 3.0 V | 2.1 | - | - | 2.1 | - | 2.1 | - | V |
| | | V _{CC} = 5.5 V | 3.85 | - | - | 3.85 | - | 3.85 | - | V |
| V _{IL} | LOW-level | V _{CC} = 2.0 V | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| | input voltage | V _{CC} = 3.0 V | - | - | 0.9 | - | 0.9 | - | 0.9 | V |
| | | V _{CC} = 5.5 V | - | - | 1.65 | - | 1.65 | - | 1.65 | V |
| V _{OH} | HIGH-level | $V_I = V_{IH} \text{ or } V_{IL}$ | | | | | | | | |
| | output voltage | I_{O} = –50 $\mu\text{A};$ V_{CC} = 2.0 V | 1.9 | 2.0 | - | 1.9 | - | 1.9 | - | V |
| | | I_{O} = –50 $\mu A;$ V_{CC} = 3.0 V | 2.9 | 3.0 | - | 2.9 | - | 2.9 | - | V |
| | | I_{O} = –50 $\mu A;$ V_{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V |
| | | $I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.58 | - | - | 2.48 | - | 2.40 | - | V |
| | | I_{O} = -8.0 mA; V_{CC} = 4.5 V | 3.94 | - | - | 3.8 | - | 3.70 | - | V |
| V _{OL} | LOW-level | $V_{I} = V_{IH} \text{ or } V_{IL}$ | | | | | | | | |
| | output voltage | $I_{O} = 50 \ \mu A; \ V_{CC} = 2.0 \ V$ | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | $I_0 = 50 \ \mu A; \ V_{CC} = 3.0 \ V$ | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | $I_0 = 50 \ \mu A; \ V_{CC} = 4.5 \ V$ | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I_{O} = 4.0 mA; V_{CC} = 3.0 V | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| | | I_{O} = 8.0 mA; V_{CC} = 4.5 V | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| l _l | input leakage current | $V_I = 5.5 V \text{ or GND};$ $V_{CC} = 0 V \text{ to } 5.5 V$ | - | - | 0.1 | - | 1.0 | - | 2.0 | μA |
| I _{CC} | supply current | | - | - | 1.0 | - | 10 | - | 40 | μΑ |
| CI | input capacitance | | - | 1.5 | 10 | - | 10 | - | 10 | pF |

11. Dynamic characteristics

Table 8.Dynamic characteristics

GND = 0 V. For test circuit see Figure 6.

| Symbol | Parameter | Conditions | | 25 °C | | −40 °C to +85 °C | | –40 °C to +125 °C | | Unit | |
|--------------------------------------|-------------------------------------|---|------------|-------|-----|-------------------------|-----|-------------------|-----|------|----|
| | | | | Min | Тур | Max | Min | Max | Min | Max | |
| t _{pd} propagation delay | propagation delay | A and B to Y; see <u>Figure 5</u> | <u>[1]</u> | | | | | | | | |
| | | V_{CC} = 3.0 V to 3.6 V | [2] | | | | | | | | |
| | | C _L = 15 pF | | - | 4.6 | 8.8 | 1.0 | 10.5 | 1.0 | 12.0 | ns |
| | | $C_L = 50 \text{ pF}$ | | - | 6.5 | 12.3 | 1.0 | 14.0 | 1.0 | 16.0 | ns |
| | | V_{CC} = 4.5 V to 5.5 V | [3] | | | | | | | | |
| | | C _L = 15 pF | | - | 3.2 | 5.9 | 1.0 | 7.0 | 1.0 | 8.0 | ns |
| | | $C_L = 50 \text{ pF}$ | | - | 4.6 | 7.9 | 1.0 | 9.0 | 1.0 | 10.5 | ns |
| C _{PD} | power dissipation capacitance | per buffer; $C_L = 50 \text{ pF}; \text{ f} = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$ | <u>[4]</u> | - | 17 | - | - | - | - | - | pF |

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] Typical values are measured at $V_{CC} = 3.3$ V.

[3] Typical values are measured at V_{CC} = 5.0 V.

[4] C_{PD} is used to determine the dynamic power dissipation P_D (μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma(C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

 f_i = input frequency in MHz; f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in Volts

12. Waveforms

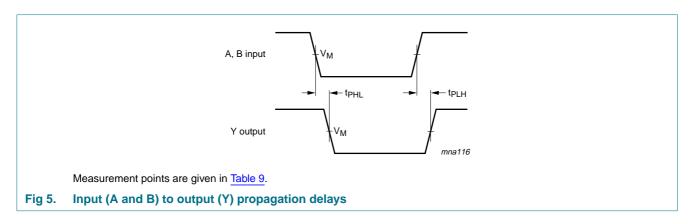


Table 9.Measurement point

| Туре | Input | | Output | |
|---------|------------------------|---------------------|--------------------|--|
| | VI | V _M | V _M | |
| XC7SH08 | GND to V _{CC} | $0.5 \times V_{CC}$ | $0.5 	imes V_{CC}$ | |

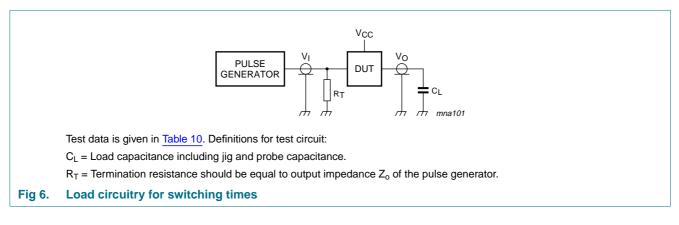


Table 10. Test data

| Туре | Input | | Load | Test |
|---------|-----------------|---------------------------------|--------------|-------------------------------------|
| | VI | t _r , t _f | CL | |
| XC7SH08 | V _{CC} | ≤ 3.0 ns | 15 pF, 50 pF | t _{PLH} , t _{PHL} |

13. Package outline

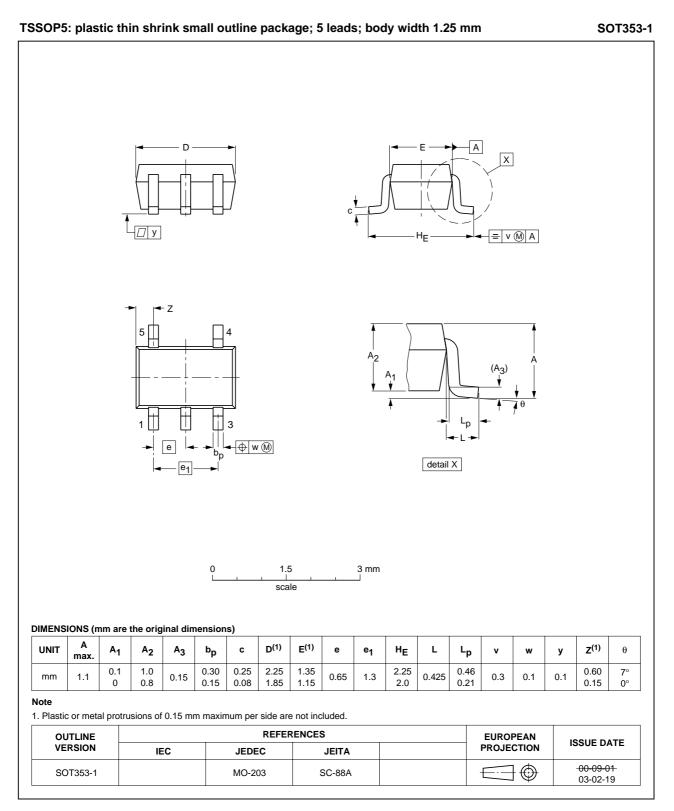
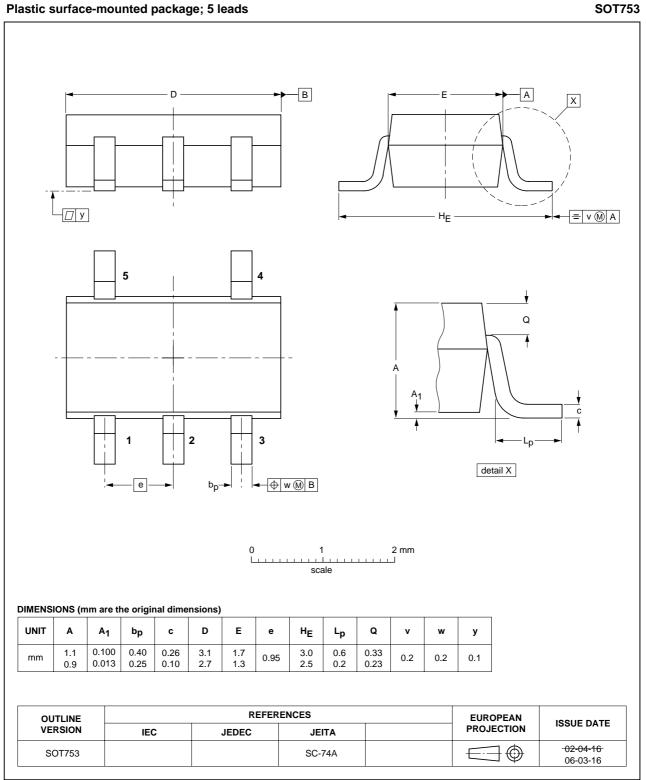


Fig 7. Package outline SOT353-1 (TSSOP5)



Plastic surface-mounted package; 5 leads

Package outline SOT753 (SC-74A) Fig 8.

14. Abbreviations

| Table 11. | Abbreviations |
|-----------|-----------------------------|
| Acronym | Description |
| CDM | Charged Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

15. Revision history

| Table 12. Revision history | | | | | | | | | |
|----------------------------|--------------|--------------------|---------------|------------|--|--|--|--|--|
| Document ID | Release date | Data sheet status | Change notice | Supersedes | | | | | |
| XC7SH08_1 | 20090901 | Product data sheet | - | - | | | | | |

16. Legal information

16.1 Data sheet status

| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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